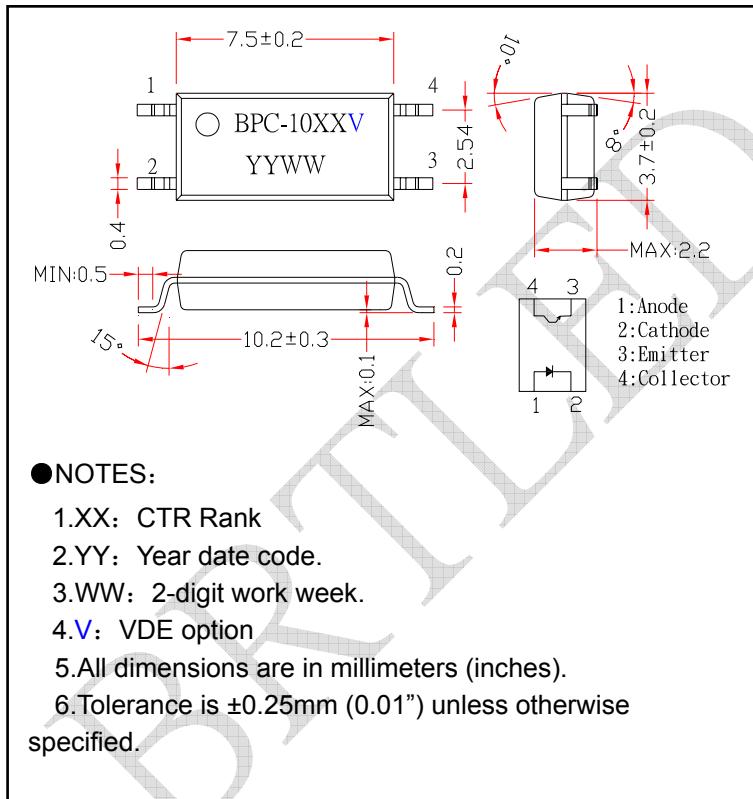


● Features:

1. Current transfer ratio:
(CTR:50~600% at $I_F=5\text{mA}$, $V_{CE}=5\text{V}$)
2. High input-output isolation voltage
($V_{iso}=5,000\text{Vrms}$)
3. Creepage distance >8mm
4. Long Mini-flat package:2.3mm profile
5. UL/CUL approved:E236324
6. VDE approved:40007240
7. CQC approved:CQC18001204187
8. This product doesn't contain restriction substance,comply RoHS standard

● Outline Dimensions



● Description

1. The BPC-10XX series are optically coupled isolators containing a infrared emitting diode and an NPN silicon phototransistor
2. The lead pitch is 2.54mm

● Applications:

- 1.Programmable controllers.
- 2.System appliances, measuring instruments.
- 3.Hybrid substrates that require high density mounting
- 4.Telecommunication equipments
- 5.Fast charger
- 6.Electric home appliances, such as fan heaters, etc.
- 7.Signal transmission between circuits of different potentials and impedances.

● Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit
INPUT	Forward Current	I_F	60	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	100	mW
OUTPUT	Collector-Emitter Voltage	V_{CEO}	80	V
	Emitter- Collector Voltage	V_{ECO}	7	
	Collector Current	I_C	50	mA
	Collector Power Dissipation	P_C	150	mW
Total Power Dissipation		P_{tot}	250	mW
*1 Isolation Voltage		V_{iso}	5,000	Vrms
Operating Temperature		T_{opr}	-30 to + 110	°C
Storage Temperature		T_{stg}	-55 to + 125	
*2 Soldering Temperature		T_{sol}	260	

*1. AC For minute, R.H. =40~60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds



●Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
INPUT	Forward Voltage	V _F	I _F =50mA	---	1.25	1.5	V
	Reverse Current	I _R	V _R =6V	---	---	10	μA
	Terminal Capacitance	C _t	V=0, f=1KHz	---	50	---	pF
OUTPUT	Collector Dark Current	I _{CEO}	V _{CE} =20V, I _F =0	---	---	100	nA
	Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =0.1mA I _F =0	80	---	---	V
	Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E =100μA I _F =0	7	---	---	V
TRANSFER CHARACTERISTICS	Collector Current	I _c	I _F =5mA V _{CE} =5V	2.5	---	30	mA
	*1 Current Transfer Ratio	CTR		50	---	600	%
	Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _F =10mA I _C = 1mA	---	---	0.3	V
	Isolation Resistance	R _{iso}	DC500V 40~60%R.H.	5×10 ¹⁰	1×10 ¹¹	---	Ω
	Floating Capacitance	C _f	V=0, f=1MHz	---	0.6	1	pF
	Response Time(Rise)	t _r	V _{CE} =2V, I _C =2mA R _L =100Ω	---	---	18	μs
	Response Time(Fall)	t _f		---	---	18	μs

*1 CTR= $I_c / I_F \times 100\%$

●RANK TABLE OF CURRENT TRANSFER RATIO(CTR)

CTR Rank	Min	Typ	Max	Unit	Condition
BPC-1000	50	-	600	% I _F =5mA, V _{CE} =5V	I _F =5mA, V _{CE} =5V
BPC-1007	80	-	160		
BPC-1008	130	-	260		
BPC-1009	200	-	400		
BPC-1002	22	-	-	% I _F =1mA, V _{CE} =5V	I _F =1mA, V _{CE} =5V
BPC-1003	34	-	-		
BPC-1014	56	-	-		
BPC-1002	63	-	125	% I _F =10mA, V _{CE} =5V	I _F =10mA, V _{CE} =5V
BPC-1003	100	-	200		
BPC-1014	160	-	320		

Characteristics Curves

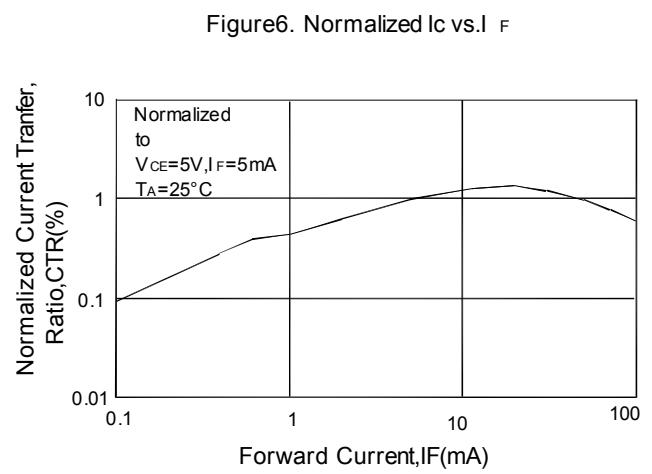
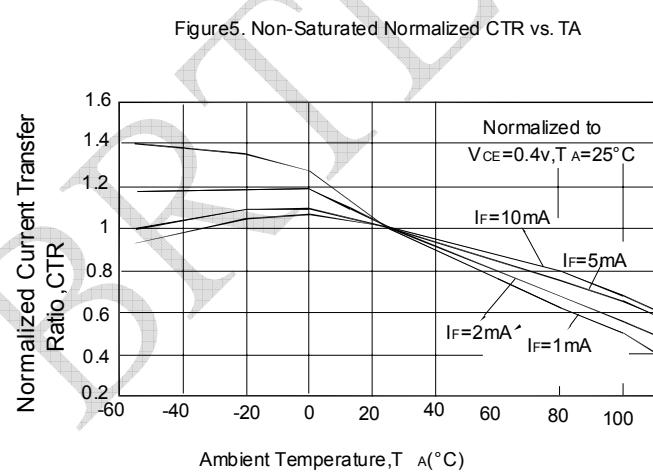
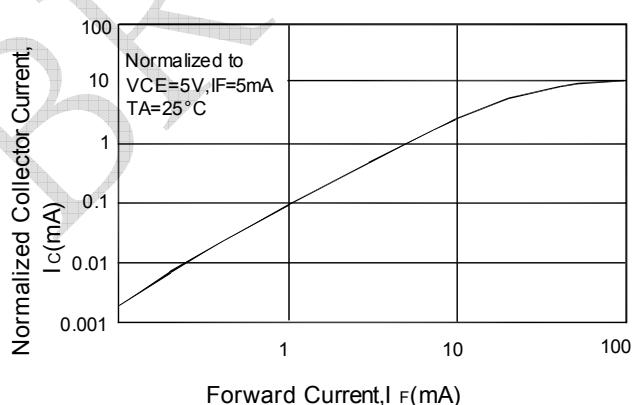
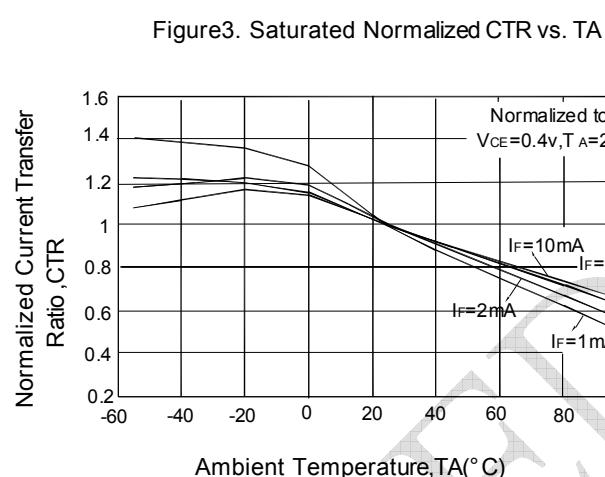
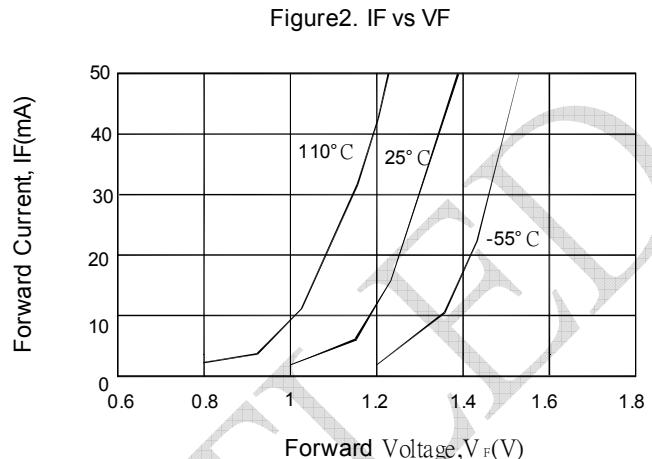
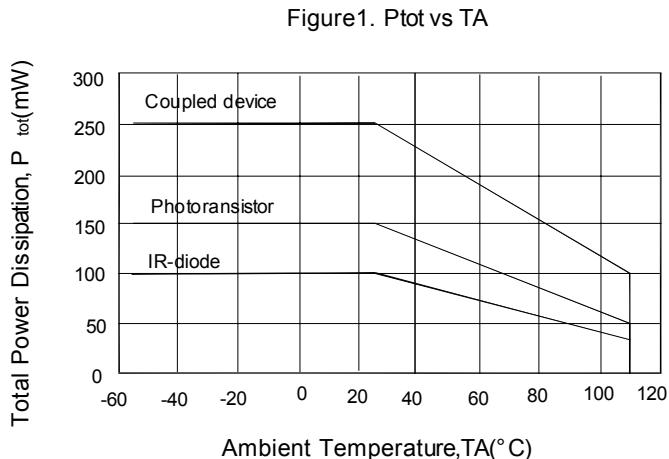


Figure7. I_{CEO} vs. T_A

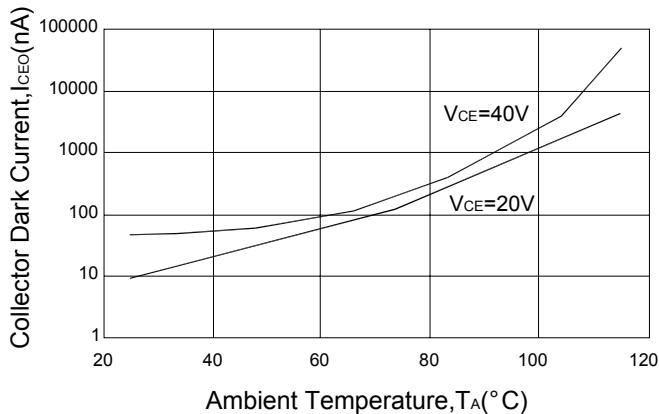


Figure8. T_{ON}/T_{OFF} vs. I_F

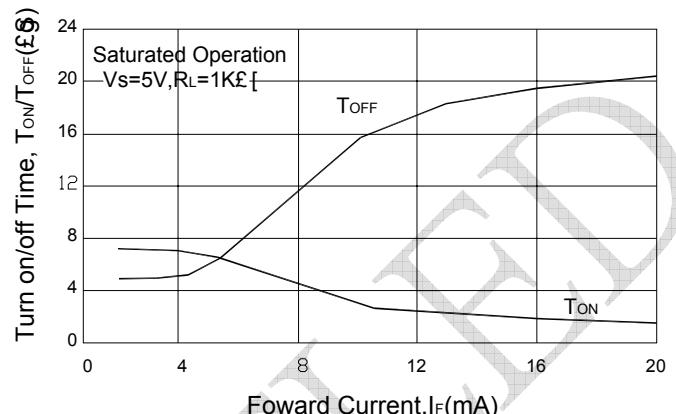


Figure9. I_C vs. V_{CE}

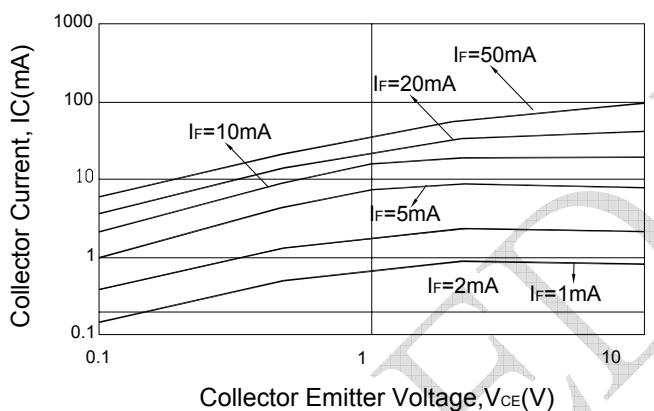


Figure10.Frequency Response

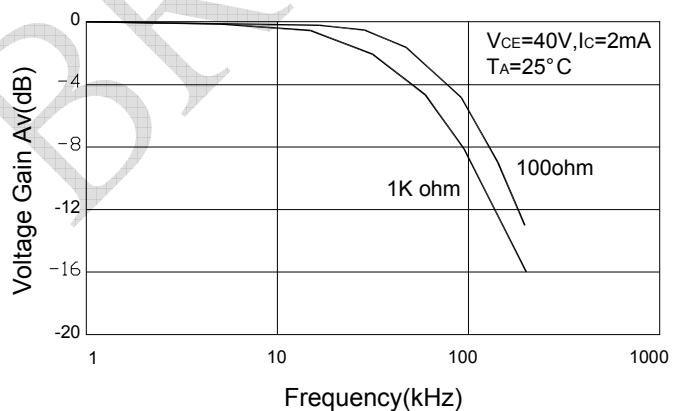
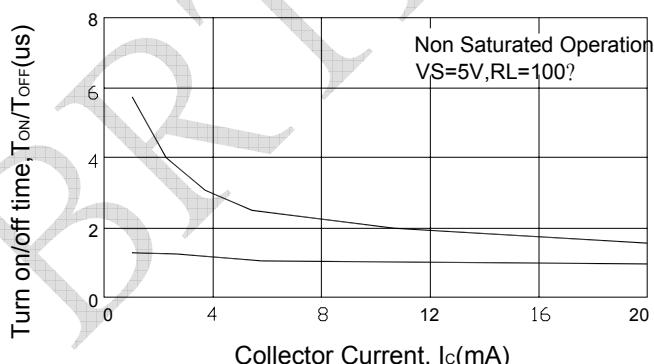
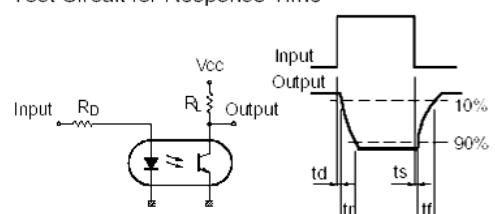


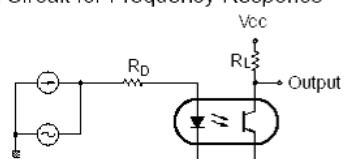
Figure11. T_{ON}/T_{OFF} vs. I_C



Test Circuit for Response Time



Test Circuit for Frequency Response





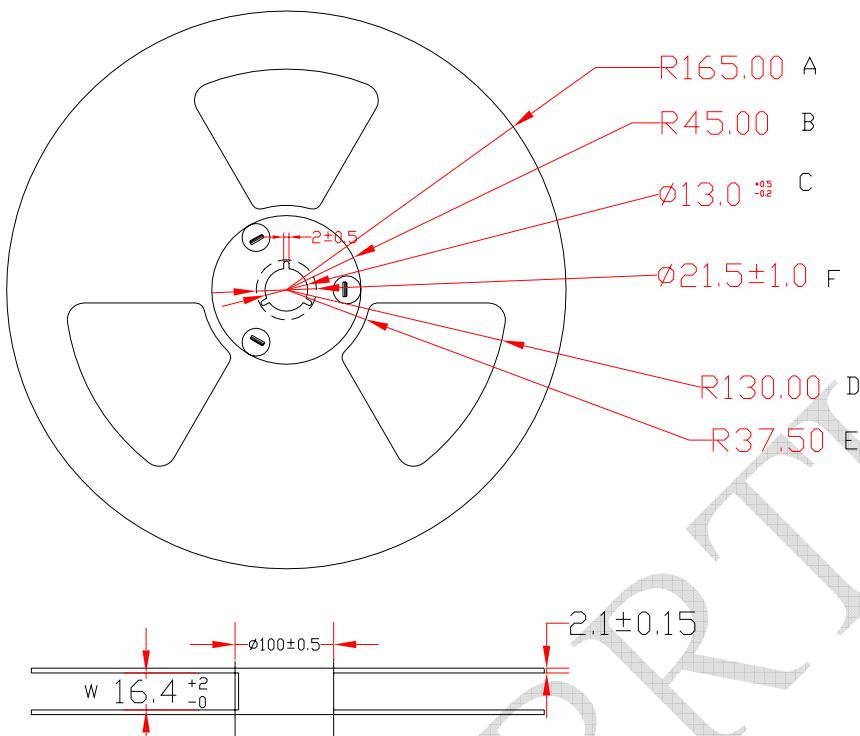
● Reliability Test

Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 :B-1	Connect with a power If=50mA Ta=Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Reverse Bias (H3TRB)	JIS C 7021 :B-11	Ta=+85°C±5°C, RH=85% PTR=V _{CE} absolute max rating*80% Test time=1000hrs	0/20
	High Temperature Reverse Bias (HTRB)	JIS C 7021 :B- 8	Ta=+105°C±5°C PTR=V _{CE} absolute max rating Test time=1000hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS C 7021 :B-10	High Ta=+125°C±5°C Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-55°C±5°C Test time=1,000hrs	0/20
	Autoclave	JESD 22-A102-B	P=15PSIG, Ta=121°C Humi. =100%RH, 48hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS C 7021 :A-4	125°C ~ 25°C ~ -55°C ~ 25°C 30min 5min 30min 5min Test Time=20cycle	0/20
	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	125°C ~-55°C 20min 20min Test Time=20cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS C 7021 :A-1	Operation heating : 260°C, within 10±1seconds.	0/20
	Solder Ability	MIL-S-883:2003 JIS C 7021 :A-2	Operation heating : 235°C, within 5±1seconds.	0/20

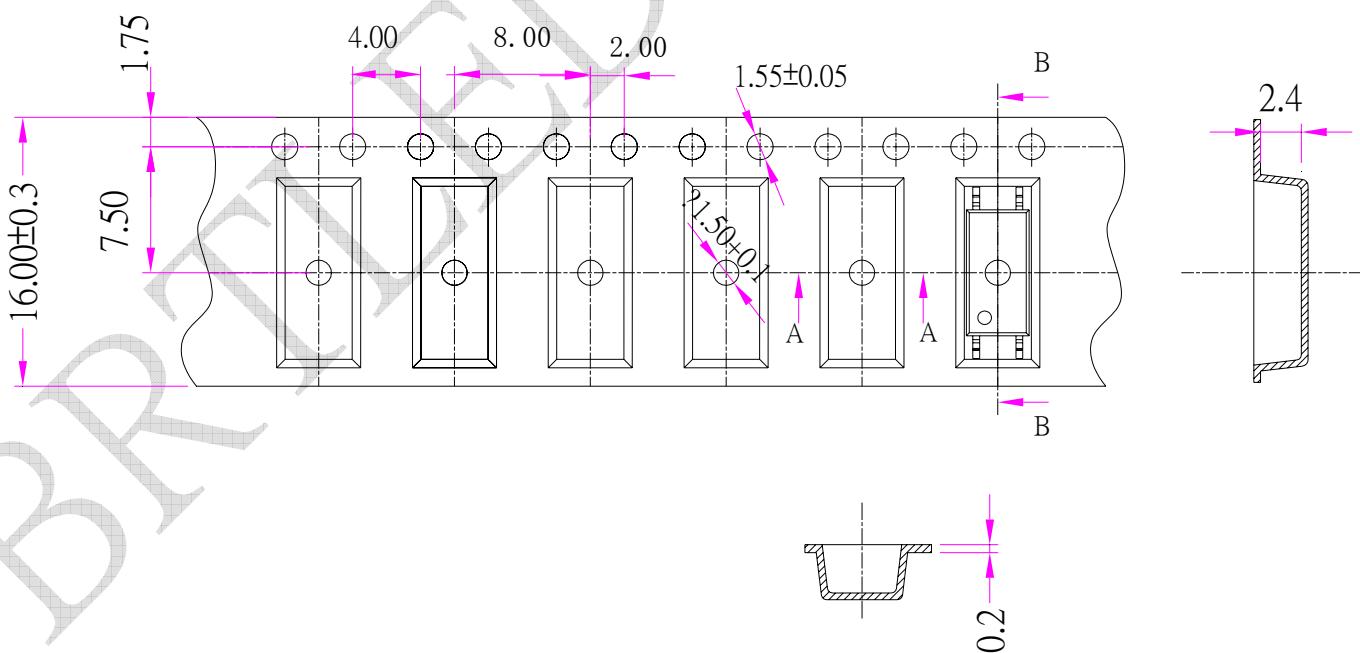
● Judgment Criteria Of Failure For The Reliability

Symbol	Measuring conditions	Judgment criteria for failure
V _F (V)	I _F =20mA	Over Ux1.0
I _r (μA)	V _r =6V	Over Ux1.0
CTR(%)	I _F =5mA, V _{CE} =5V	Shift>1.2
V _{CE(sat)}	I _F =20mA, I _C = 1mA	Over Ux1.0
BV _{CEO}	I _C =0.1mA, I _F =0	Over Lx1.0
BV _{ECO}	I _E =10μA, I _F =0	Over Lx1.0

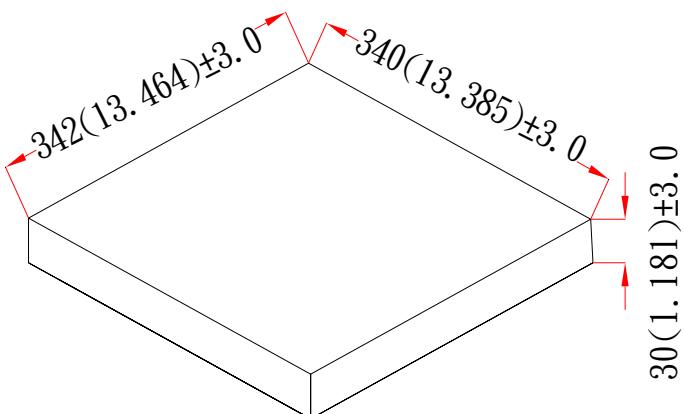
● **Packaging Box Dimensions (Units: mm)**



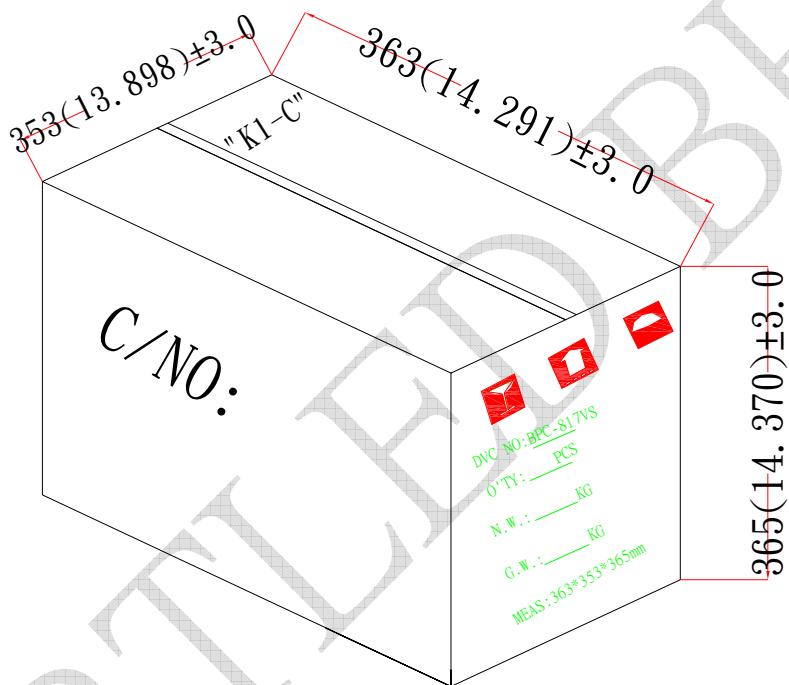
● **Packaging Tube Dimensions**



● Inner box



● Carton



Notes:

- 1、3000 PCS per reel, 10reels per Carton.
- 2、All dimensions are in millimeters (inches).
3. Tolerance is $\pm 0.10\text{mm}$ (0.004") unless otherwise specified.
- 4、Specifications are subject to change without notice.